VS-8EWS..SPbF Series



Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum average forward current	I _{F(AV)}	T_C = 105 °C, 180° conduction half sine wave	8						
Maximum peak one cycle non-repetitive surge current		10 ms sine pulse, rated V_{RRM} applied	125	А					
	I _{FSM}	10 ms sine pulse, no voltage reapplied	150						
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	78	A ² s					
Maximum 1-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	110	A-5					
Maximum I ² √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	1100	A²√s					

ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS					
Maximum forward voltage drop	V _{FM}	8 A, T _J = 25 °C		1.1	V				
Forward slope resistance	r _t	T _{.1} = 150 °C	20	mΩ					
Threshold voltage	V _{F(TO)}	$I_{\rm J} = 150$ C	0.82	V					
Maximum reverse leakage current		T _J = 25 °C	0.05	mA					
Maximum reverse leakage current	IRM	T _J = 150 °C	V _R = Rated V _{RRM}	0.50	ШA				

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	°C / M	
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA (1)}		62	°C/W	
Approvimento weight			1	g	
Approximate weight			0.03	oz.	
Marking device		Case style TO-252AA (D-PAK)	8EWS	S12S	

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994



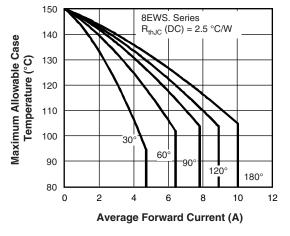


Fig. 1 - Current Rating Characteristics

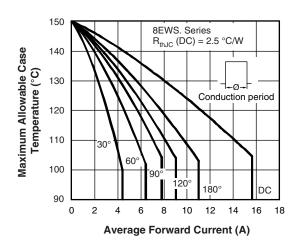


Fig. 2 - Current Rating Characteristics

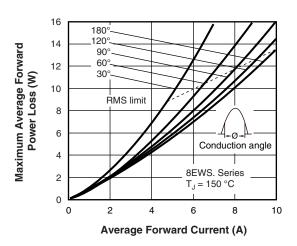


Fig. 3 - Forward Power Loss Characteristics

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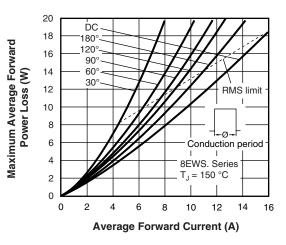
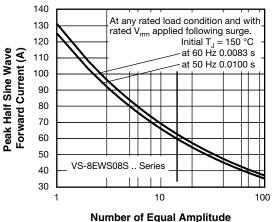


Fig. 4 - Forward Power Loss Characteristics



Half Cycle Current Pulses (N)



160 Maximum non-repetitive surge current versus pulse train duration. 140 Initial $T_J = T_J$ max. No voltage reapplied Peak Half Sine Wave Forward Current (A) 120 Rated V_{rrm} reapplied 100 80 60 40 VS-8EWS08S .. Series 20 0.01 0.1 10 1 Pulse Train Duration (s)

Fig. 6 - Maximum Non-Repetitive Surge Current

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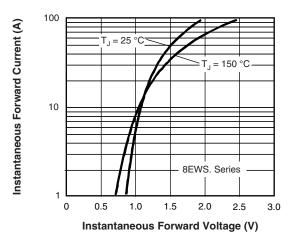


Fig. 7 - Forward Voltage Drop Characteristics

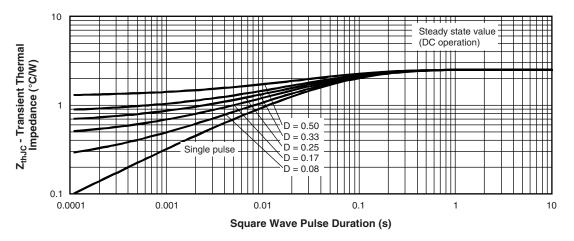


Fig. 8 - Thermal Impedance ZthJC Characteristics



		 TRR = tape and reel (right oriented)
		 TRL = tape and reel (left oriented)
9	-	PbF = lead (Pb)-free

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95016						
Part marking information	www.vishay.com/doc?95059						
Packaging information	www.vishay.com/doc?95033						

ORDERING INFORMATION TABLE

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Device code	VS-	8	Е	w	s	12	S	TR	PbF
	1	2	3	4	5	6	7	8	9
	1 - 2 - 3 - 4 - 5 -	Cur Circ E = Pac W = Typ	rent rati cuit confi single c kage: D-PAK e of silic	con:	8 A) n:				
	6 - 7 - 8 -	Volf S = • TF • TF	tage rati surface R = tape RR = tap	d recover ngs — mounta and ree be and re	ible el eel (righ	t oriente			

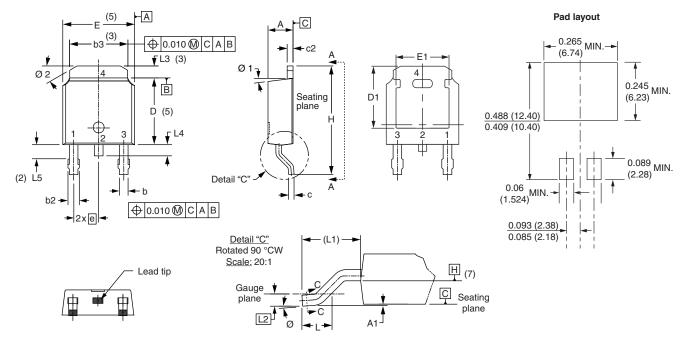
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D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51 BSC		0.020 BSC		
с	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

(2) Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

⁽⁸⁾ Outline conforms to JEDEC outline TO-252AA

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